



CD4042BM/CD4042BC Quad Clocked D Latch

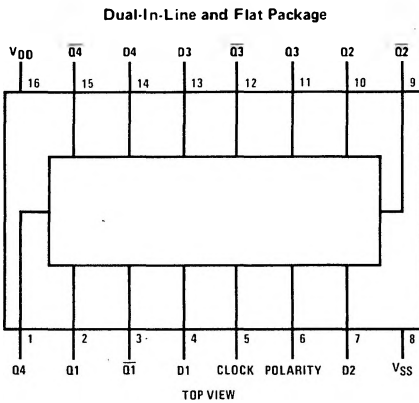
General Description

The CD4042BM/CD4042BC quad clocked "D" latch is a monolithic complementary MOS (CMOS) integrated circuit constructed with P- and N-channel enhancement mode transistors. The outputs Q and \bar{Q} either latch or follow the data input depending on the clock level which is programmed by the polarity input. For polarity = 0; the information present at the data input is transferred to Q and \bar{Q} during 0 clock level; and for polarity = 1, the transfer occurs during the 1 clock level. When a clock transition occurs (positive for polarity = 0 and negative for polarity = 1), the information present at the input during the clock transition is retained at the outputs until an opposite clock transition occurs.

Features

- Wide supply voltage range 3.0V to 15V
- High noise immunity 0.45 V_{DD} (typ.)
- Low power TTL compatibility fan out of 2 driving 74L or 1 driving 74LS
- Clock polarity control
- Fully buffered data inputs
- Q and \bar{Q} outputs

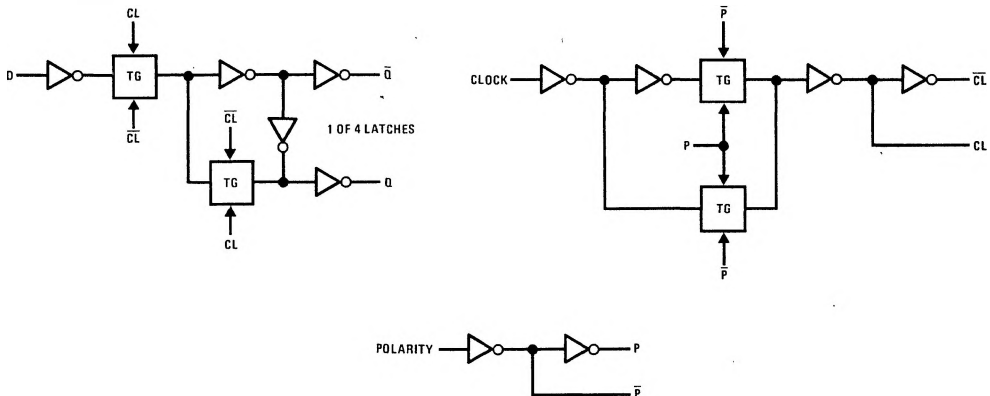
Connection Diagram



Truth Table

CLOCK	POLARITY	Q
0	0	D
	0	Latch
1	1	D
	1	Latch

Logic Diagrams



Absolute Maximum Ratings

(Notes 1 and 2)

V _{DD} Supply Voltage	-0.5V to +18V
V _{IN} Input Voltage	-0.5V to V _{DD} + 0.5V
T _S Storage Temperature Range	-65°C to +150°C
P _D Package Dissipation	500 mW
T _L Lead Temperature (Soldering, 10 seconds)	300°C

Recommended Operating Conditions

(Note 2)

V _{DD} Supply Voltage	3V to 15V
V _{IN} Input Voltage	0V to V _{DD}
T _A Operating Temperature Range	-55°C to +125°C
CD4042BM	-40°C to +85°C
CD4042BC	

DC Electrical Characteristics CD4042BM (Note 2)

PARAMETERS	CONDITIONS	-55°C		25°C			125°C		UNITS
		MIN	MAX	MIN	TYP	MAX	MIN	MAX	
I _{DD} Quiescent Device Current	V _{DD} = 5V		1		0.02	1		30	μA
	V _{DD} = 10V		2		0.02	2		60	μA
	V _{DD} = 15V		4		0.02	4		120	μA
V _{OL} Low Level Output Voltage	I _O < 1 μA, V _{IH} = V _{DD} , V _{IL} = 0V								
	V _{DD} = 5V		0.05		0	0.05		0.05	V
	V _{DD} = 10V		0.05		0	0.05		0.05	V
V _{OH} High Level Output Voltage	I _O < 1 μA, V _{IH} = V _{DD} , V _{IL} = 0V								
	V _{DD} = 5V	4.95		4.95	5		4.95		V
	V _{DD} = 10V	9.95		9.95	10		9.95		V
V _{IL} Low Level Input Voltage	I _O < 1 μA								
	V _{DD} = 5V, V _O = 0.5V or 4.5V		1.5		2.25	1.5		1.5	V
	V _{DD} = 10V, V _O = 1V or 9V		3.0		4.5	3.0		3.0	V
V _{IH} High Level Input Voltage	I _O < 1 μA								
	V _{DD} = 5V, V _O = 0.5V or 4.5V	3.5		3.5	2.75		3.5		V
	V _{DD} = 10V, V _O = 1V or 9V	7.0		7.0	5.5		7.0		V
I _{OL} Low Level Output Current	V _{IH} = V _{DD} , V _{IL} = 0V								
	V _{DD} = 5V, V _O = 0.4V	0.64		0.51	0.88		0.36		mA
	V _{DD} = 10V, V _O = 0.5V	1.6		1.3	2.25		0.9		mA
I _{OH} High Level Output Current	V _{IH} = V _{DD} , V _{IL} = 0V								
	V _{DD} = 5V, V _O = 4.6V	-0.64		-0.51	-0.88		-0.36		mA
	V _{DD} = 10V, V _O = 9.5V	-1.6		-1.3	-2.25		-0.9		mA
I _{IN} Input Current	V _{DD} = 15V, V _{IN} = 0V		-0.1		-10 ⁻⁵	-0.1		-1.0	μA
	V _{DD} = 15V, V _{IN} = 15V		0.1		10 ⁻⁵	0.1		1.0	μA

DC Electrical Characteristics CD4042BC (Note 2)

PARAMETER	CONDITIONS	-40°C		25°C			85°C		UNITS
		MIN	MAX	MIN	TYP	MAX	MIN	MAX	
I _{DD} Quiescent Device Current	V _{DD} = 5V		4		0.02	4		30	μA
	V _{DD} = 10V		8		0.02	8		60	μA
	V _{DD} = 15V		16		0.02	16		120	μA
V _{OL} Low Level Output Voltage	I _O < 1 μA, V _{IH} = V _{DD} , V _{IL} = 0V								
	V _{DD} = 5V		0.05		0	0.05		0.05	V
	V _{DD} = 10V		0.05		0	0.05		0.05	V
V _{OH} High Level Output Voltage	I _O < 1 μA, V _{IH} = V _{DD} , V _{IL} = 0V								
	V _{DD} = 5V	4.95		4.95	5		4.95		V
	V _{DD} = 10V	9.95		9.95	10		9.95		V
V _{IL} Low Level Input Voltage	I _O < 1 μA								
	V _{DD} = 5V, V _O = 0.5V or 4.5V		1.5		2.25	1.5		1.5	V
	V _{DD} = 10V, V _O = 1V or 9V		3.0		4.5	3.0		3.0	V
V _{IH} High Level Input Voltage	I _O < 1 μA								
	V _{DD} = 5V, V _O = 0.5V or 4.5V	3.5		3.5	2.75		3.5		V
	V _{DD} = 10V, V _O = 1V or 9V	7.0		7.0	5.5		7.0		V

DC Electrical Characteristics (Cont'd.) CD4042BC (Note 2)

PARAMETER	CONDITIONS	-40°C		25°C			85°C		UNITS
		MIN	MAX	MIN	TYP	MAX	MIN	MAX	
V _{IH} High Level Input Voltage	I _{OI} < 1 μA								
	V _{DD} = 5V, V _O = 0.5V or 4.5V	3.5		3.5	2.75		3.5		V
	V _{DD} = 10V, V _O = 1V or 9V	7.0		7.0	5.5		7.0		V
	V _{DD} = 15V, V _O = 1.5V or 13.5V	11.0		11.0	8.25		11.0		V
I _{OL} Low Level Output Current	V _{IH} = V _{DD} , V _{IL} = 0V								
	V _{DD} = 5V, V _O = 0.4V	0.52		0.44	0.88		0.36		mA
	V _{DD} = 10V, V _O = 0.5V	1.3		1.1	2.25		0.9		mA
	V _{DD} = 15V, V _O = 1.5V	3.6		3.0	8.8		2.4		mA
I _{OH} High Level Output Current	V _{IH} = V _{DD} , V _{IL} = 0V								
	V _{DD} = 5V, V _O = 4.6V	-0.52		-0.44	-0.88		-0.36		mA
	V _{DD} = 10V, V _O = 9.5V	-1.3		-1.1	-2.25		-0.9		mA
	V _{DD} = 15V, V _O = 13.5V	-3.6		-3.0	-8.8		-2.4		mA
I _{IN} Input Current	V _{DD} = 15V, V _{IN} = 0V		-0.3		-10 ⁻⁵	-0.3		-1.0	μA
	V _{DD} = 15V, V _{IN} = 15V		0.3		10 ⁻⁵	0.3		1.0	μA

AC Electrical Characteristics T_A = 25°C, C_L = 50pF, R_L = 200k, Input t_r = t_f = 20ns, unless otherwise specified

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
t _{PHL} , t _{PLH}	Propagation Delay Time Data In to Q	V _{DD} = 5V V _{DD} = 10V V _{DD} = 15V	175	350	ns
			75	150	ns
			60	120	ns
t _{PHL} , t _{PLH}	Propagation Delay Time Data In to \bar{Q}	V _{DD} = 5V V _{DD} = 10V V _{DD} = 15V	150	300	ns
			75	150	ns
			50	100	ns
t _{PHL} , t _{PLH}	Propagation Delay Time Clock to Q	V _{DD} = 5V V _{DD} = 10V V _{DD} = 15V	250	500	ns
			100	200	ns
			80	160	ns
t _{PHL} , t _{PLH}	Propagation Delay Time Clock to \bar{Q}	V _{DD} = 5V V _{DD} = 10V V _{DD} = 15V	250	500	ns
			115	230	ns
			90	180	ns
t _H	Minimum Hold Time	V _{DD} = 5V V _{DD} = 10V V _{DD} = 15V	60	120	ns
			30	60	ns
			25	50	ns
t _{SU}	Minimum Set-Up Time	V _{DD} = 5V V _{DD} = 10V V _{DD} = 15V	0	50	ns
			0	30	ns
			0	25	ns
t _W	Minimum Clock Pulse Width	V _{DD} = 5V V _{DD} = 10V V _{DD} = 15V	100	200	ns
			50	100	ns
			30	60	ns
t _{THL} , t _{TLH}	Transition Time	V _{DD} = 5V V _{DD} = 10V V _{DD} = 15V	125	250	ns
			60	125	ns
			50	100	ns
C _{IN}	Input Capacitance	Any Input	5.0	7.5	pF

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and "Electrical Characteristics" provide conditions for actual device operation.

Note 2: V_{SS} = 0V unless otherwise specified.

Note 3: Being a latch, the CD4042BM/CD4042BC is not clock rise and fall time sensitive.

Switching Time Waveforms

